Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

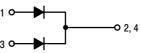
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for

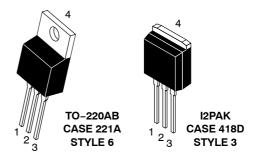


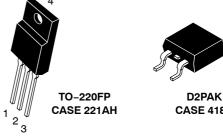
ON Semiconductor®

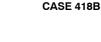
http://onsemi.com

PIN CONNECTIONS









ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (Rated V _R , T _C = 130°C)	Per device Per diode	I _{F(AV)}	20 10	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 125°C)	Per device Per diode	I _{FRM}	40 20	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	150	А
Operating Junction Temperature		T _J	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/µs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Rating	Symbol	NTST20U100CTG, NTSB20U100CT-1G	NTSB20U100CTG	NTSJ20U100CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	000	2.5 70	1.24 46.7	4.20 105	°C/W °C/W

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1)	v _F			V
$(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$ $(I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$		0.55 0.65	- 0.79	
(IF = 10 A, 1J = 25 O)		0.05	0.79	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$		0.50	_	
(I _F = 10 A, T _J = 125°C)		0.58	0.68	
Maximum Instantaneous Reverse Current (Note 1)	I_{R}			
$(V_R = 70 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_R = 70 \text{ V}, T_J = 125^{\circ}\text{C})$		17 5.3	_	μA mA
(VR = 70 V, TJ = 123 O)		5.5	_	IIIA
(Rated dc Voltage, T _J = 25°C)		-	800	μΑ
(Rated dc Voltage, T _J = 125°C)		12	25	mA

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

TYPICAL CHARACTERISITICS

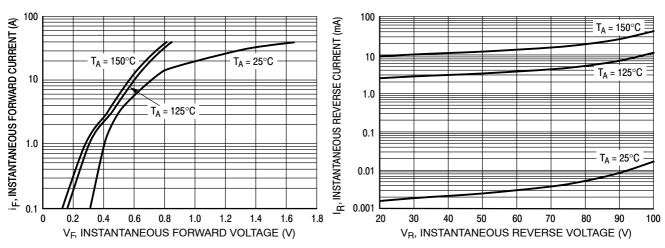


Figure 1. Typical Instantaneous Forward Characteristics

Figure 2. Typical Reverse Characteristics

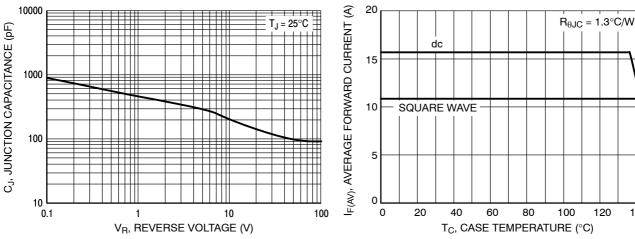
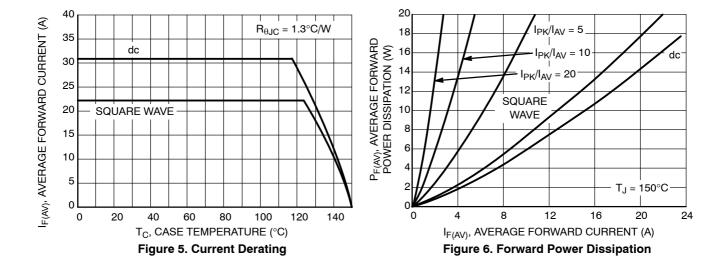




Figure 4. Current Derating per Leg

140



TYPICAL CHARACTERISITICS

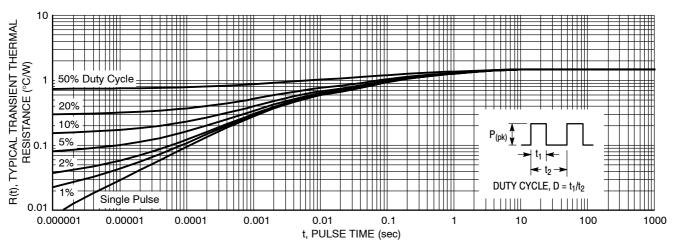


Figure 7. Typical Transient Thermal Response for NTST20U100CT and NTSB20U100CT-1G

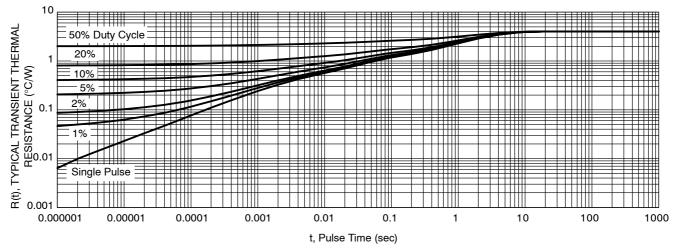


Figure 8. Typical Transient Thermal Response, Junction-to-Case for NTSJ20U100CTG

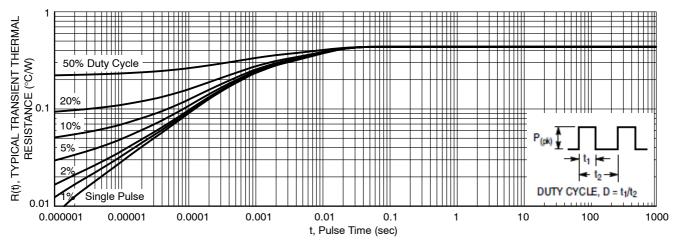
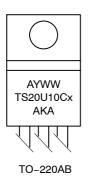


Figure 9. Typical Transient Thermal Response for NTSB20U100CTG

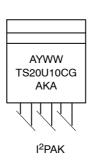
ORDERING INFORMATION

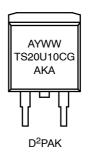
Device	Package	Shipping
NTST20U100CTG	TO-220AB (Pb-Free)	50 Units / Rail
NTSB20U100CT-1G	I ² PAK (Pb-Free)	50 Units / Rail
NTSJ20U100CTG	TO-220FP (Halide-Free)	50 Units / Rail
NTSB20U100CTG	D ² PAK (Pb-Free)	50 Units / Rail
NTSB20U100CTT4G	D ² PAK (Pb-Free)	800 / Tape & Reel

MARKING DIAGRAMS









A = Assembly Location

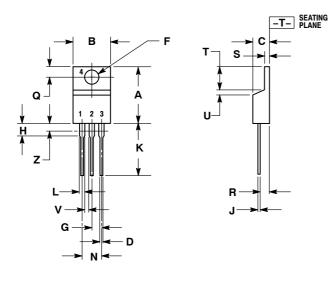
Y = Year
WW = Work Week
AKA = Polarity Designator

x = G or H

G = Pb-Free Package H = Halide-Free Package

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**



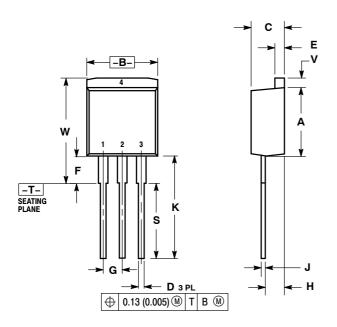
NOTES:

- IES:
 DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION Z DEFINES A ZONE WHERE ALL
 BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04
STYLE 6: PIN 1. ANODE 2. CATHODE				
3. ANODE				

- CATHODE

I²PAK (TO-262) CASE 418D ISSUE D



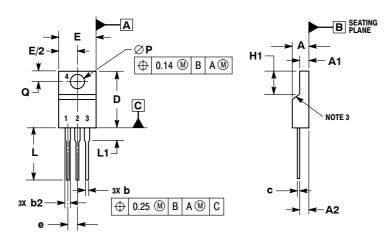
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.335	0.380	8.51	9.65
В	0.380	0.406	9.65	10.31
C	0.160	0.185	4.06	4.70
D	0.026	0.035	0.66	0.89
Е	0.045	0.055	1.14	1.40
F	0.122 REF		3.10 REF	
G	0.100 BSC		2.54	BSC
Н	0.094	0.110	2.39	2.79
J	0.013	0.025	0.33	0.64
K	0.500	0.562	12.70	14.27
S	0.390 REF		9.90	REF
٧	0.045	0.070	1.14	1.78
W	0.522	0.551	13.25	14.00

PACKAGE DIMENSIONS

TO-220 FULLPACK, 3-LEAD CASE 221AH **ISSUE B**



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

- Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. CONTOUR UNCONTROLLED IN THIS AREA.

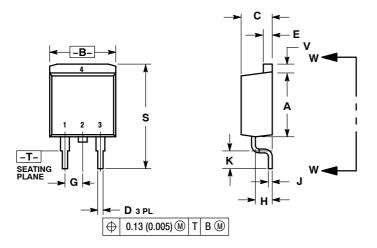
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.

 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.
- SHALL NOT EXCEED 2.00.

	8411 1 18			
	MILLIMETERS			
DIM	MIN	MAX		
Α	4.30	4.70		
A1	2.50	2.90		
A2	2.50	2.70		
b	0.54	0.84		
b2	1.10	1.40		
C	0.49	0.79		
D	14.70	15.30		
E	9.70	10.30		
е	2.54 BSC			
H1	6.70	7.10		
L	12.70	14.73		
L1		2.80		
P	3.00	3.40		
Q	2.80	3.20		

PACKAGE DIMENSIONS

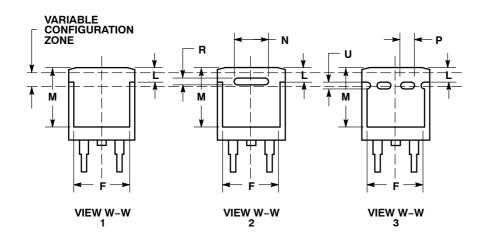
D²PAK 3 CASE 418B-04 ISSUE K



NOTES

- DIMENSIONING AND TOLERANCING
 PER ANSI Y14.5M, 1982.
- PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
Е	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54 BSC	
Н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
M	0.280	0.320	7.11	8.13
N	0.197	0.197 REF		REF
Р	0.079 REF		2.00 REF	
R	0.039	0.039 REF		REF
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40



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